

Microwave control of atomic motional states in a spin-dependent optical lattice

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Abstract. Spin-dependent optical potentials allow us to use microwave radiation to manipulate the motional state of trapped neutral atoms ([Förster et al. 2009 Phys. Rev. Lett. 103, 233001](#)). Here, we discuss this method in greater detail, comparing it to the widely-employed Raman sideband coupling method. We provide a simplified model for sideband cooling in a spin-dependent potential, and we discuss it in terms of the generalized Lamb-Dicke parameter. Using a master equation formalism, we present a quantitative analysis of the cooling performance for our experiment, which can be generalized to other experimental settings. We additionally use microwave sideband transitions to engineer motional Fock states and coherent states, and we devise a technique for measuring the population distribution of the prepared states.

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Contents

1	Introduction	2
2	Microwave induced motional sideband transitions	3
2.1	Motional states in a state dependent lattice	3
2.2	Experimental setup	6
2.3	Microwave sideband spectra	7
3	Microwave sideband cooling	10
3.1	Raman vs. microwave sideband cooling	11
3.2	Quantitative model based on master equation	13
3.3	Experimental results	16
4	Motional state control	17
4.1	Motional state detection	17
4.2	Motional state engineering	18
5	Conclusions and outlook	20

1. Introduction

Motional state control of atomic particles is achieved by the absorption and emission cycles of a resonant or near resonant radiation, i.e., by light scattering typically at optical frequencies. For instance, laser Doppler cooling reduces the momentum of atoms or ions through multiple recoil processes [1]. Coherent momentum transfer can be performed with two-photon Raman processes [2] for applications in, e.g., atom interferometry [3].

The quantum state of the atomic particles is composed of the internal states, e.g., two spin states $\{|\uparrow\rangle, |\downarrow\rangle\}$ for a two-level atom, and the external motional state. For free particles the simplest motional state is the momentum state $|\vec{p}\rangle$. Trapped particles are instead characterized by vibrational eigenstates $|n\rangle$, which in the simplest case of a harmonic oscillator of frequency ω_{vib} have their energies equally spaced as $\hbar\omega_{\text{vib}}(n+1/2)$.

In free space, the momentum state of a particle, and consequently its kinetic energy, is changed by the momentum transfer $|\vec{p}\rangle \rightarrow |\vec{p}'\rangle$ in the absorption/emission cycle of an optical photon. While the momentum transfer picture also applies approximately for trapped particles when the energy separation between motional states is not spectroscopically resolved, recoil-free transitions become possible in the resolved-sideband regime (Mössbauer effect). While carrier transitions do not change the vibrational quantum state $|n\rangle$, the motional state can be controlled via sideband transitions $|n\rangle \rightarrow |n'\rangle$ ($n' \neq n$), for instance, in incoherent cooling processes $|n\rangle \rightarrow |n-1\rangle$ or in coherent manipulation of vibrational states [4]. With trapped ions or neutral atoms trapped in optical lattices, the resolved-sideband regime is typically realized by two-photon Raman transitions connecting two different hyperfine ground

states [5, 6, 7]. Alternatively, in spin-dependent potentials it becomes also possible to use microwave transitions, which also offer sufficient spectral resolution [8, 9, 10, 11, 12].

In the semi-classical picture shown in figure (1), an atomic transition exchanges either kinetic or potential energy with the motional degree of freedom of the atom. With the absorption of an optical photon, the kinetic energy is changed by the momentum kick from the photon, and quantum mechanically the process can be interpreted in terms of a displacement of the wavefunction in momentum space. With the absorption of a microwave photon, which carries a negligible momentum, the potential energy of the atom can be changed if the trapping potentials of the two states are different; this allows an interpretation in terms of a wavefunction displaced in position space.

2. Microwave induced motional sideband transitions

2.1. Motional states in a state dependent lattice

We consider a single atom with two spin states $\{|\uparrow\rangle, |\downarrow\rangle\}$ trapped in a one-dimensional optical lattice. We will initially ignore the internal degree of freedom of the atom and take the Hamiltonian governing its motion in the trap as given by

$$\hat{H}_{\text{ext}} = \frac{\hat{p}^2}{2m} + \frac{U_0}{2} \cos^2(k_L \hat{x}), \quad (1)$$

with U_0 being the trap depth, $k_L = 2\pi/\lambda_L$ being the wavenumber of the two counter propagating laser fields creating the lattice, and \hat{x} , \hat{p} , the atom's position and momentum, respectively.

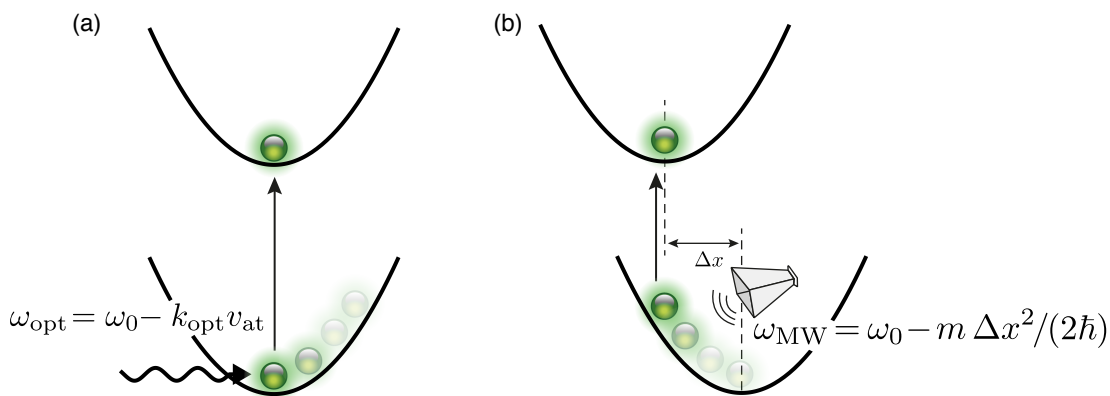


Figure 1: In a semi-classical picture, an atomic transition can affect the motional state of an atom either (a) by a kinetic energy change caused by the momentum transfer from an optical photon of wavevector k_{opt} (velocity selective transition [1]), or (b) by a potential energy change when the potentials of the two internal states are displaced in space by Δx (position selective transition). In the two cases, the motional energy is decreased when the detuning is set to the Doppler shift $k_{\text{opt}} v_{\text{at}}$ or the potential energy $m \omega^2 \Delta x^2 / (2\hbar)$, respectively.

The motional eigenstates of an atom in such a potential are the well-known Bloch wavefunctions $|\Psi_{n,k}^B\rangle$, where n is the band index ($n = 0$ for the first band) and k is the wavevector in the first Brillouin zone (BZ). In the limit of deep lattice potentials that we are considering here, the atoms remain localized for the time scales of the experiment and their spatial state is best described by the maximally localized Wannier state [13]

$$|n, r\rangle = \frac{1}{\sqrt{N}} \sum_{k \in \text{BZ}} e^{-ikrd} |\Psi_{n,k}^B\rangle. \quad (2)$$

Here N is the lattice size, r the site index, and $d = \lambda_L/2$ the lattice spacing. In this deep lattice regime, we can safely view the vanishingly narrow energy bands $\varepsilon_n(k)$ as the vibrational level energies ε_n of the corresponding Wannier state $|n, r\rangle$ at lattice site r ; in the harmonic approximation we would have $\varepsilon_n = \hbar\omega_{\text{vib}}(n + 1/2)$.

The Wannier states form an orthonormal basis set such that the overlaps between two different states yield $\langle n, r | n', r' \rangle = \delta_{n,n'} \delta_{r,r'}$. This means that the interaction of the atomic spin with a microwave field will fail to induce motional sideband transitions, $|n, r\rangle \leftrightarrow |n', r'\rangle$, because of the nearly negligible momentum carried by microwave photons, five orders of magnitude smaller than that by optical photons. This restriction can be lifted if the atom experiences a different trapping potential depending on its internal spin state as the corresponding motional eigenstates are then no longer orthogonal [14, 15]. A simple relative spatial shift of the potentials trapping each internal state induces such a difference. A shift by a distance Δx is accounted for by the position space shift operator $\hat{T}_{\Delta x} \equiv \exp(-i \hat{p} \Delta x / \hbar)$, see figure (2a). The overlap between the two Wannier states then becomes

$$\langle n', r' | \hat{T}_{\Delta x} | n, r \rangle \equiv I_{n,r}^{n',r'}(\Delta x). \quad (3)$$

The resulting overlap integral, $-1 \leq I_{n,r}^{n',r'}(\Delta x) \leq 1$, is hence a known function of Δx , see figure (2b). It is analogous to the Franck–Condon factor from molecular physics and it determines the strength of the transitions coupling different vibrational levels [16].

One way to realize the shift operator $\hat{T}_{\Delta x}$ is by two overlapped lattices which trap each spin state separately and can be independently shifted in the longitudinal direction as shown in figure (2). The trapping potential thus becomes dependent on the spin state $s = \{\uparrow, \downarrow\}$ and the shift distance $\Delta x = x_{\uparrow}^0 - x_{\downarrow}^0$,

$$\hat{H}_{\text{ext}} = \frac{\hat{p}^2}{2m} + \sum_{s=\{\uparrow, \downarrow\}} \frac{U_0^s}{2} \cos^2[k_L(\hat{x} - x_s^0)] \otimes |s\rangle \langle s| \quad (4)$$

with x_s^0 being the position of the lattice trapping the state $|s\rangle$. The total transition matrix element for two spin states coupled by an interaction Hamiltonian H_I , with a free-atom bare Rabi frequency Ω_0 , is then given by

$$\hbar \Omega_{n,r}^{n',r'}(\Delta x) / 2 = \langle s', n', r' | \hat{T}_{\Delta x} \otimes H_I | s, n, r \rangle = I_{n,r}^{n',r'}(\Delta x) \times \hbar \Omega_0 / 2. \quad (5)$$

The Franck–Condon factors $I_{n,r}^{n',r'}(\Delta x)$ can be explicitly evaluated using equations (2) and (3). We first rewrite equation (2) using Bloch’s theorem,

$$W_{n,r}(x) = \frac{1}{\sqrt{N}} \sum_{k \in \text{BZ}} \sum_{q \in \mathbb{Z}} e^{-ikrd} e^{i \frac{2\pi}{d} q} a_{n,q}(k) |k\rangle. \quad (6)$$

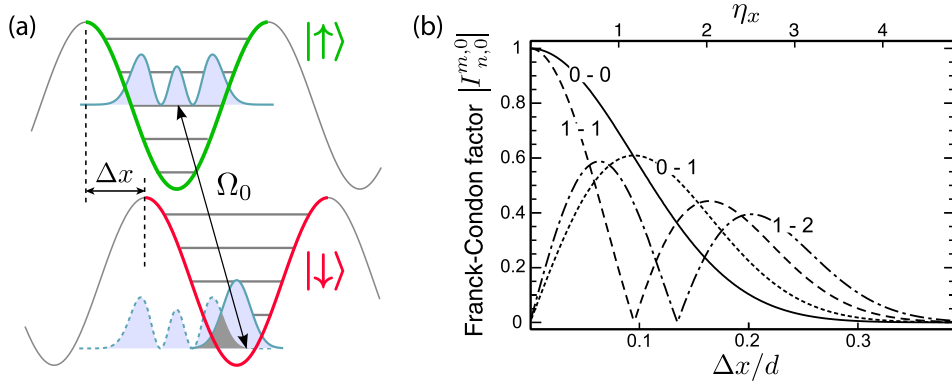


Figure 2: (a) The coupling strength of a sideband transition in a spin-dependent lattice is the bare spin state coupling Ω_0 multiplied by the overlap between the two involved vibrational states, the Franck-Condon factor, which is controlled by the relative shift Δx between the two lattices. η_x is the spatial Lamb-Dicke parameter defined in section 2.1 and later in 3.1. (b) Lattice shift dependence of the Franck-Condon factors for different transitions, denoted as $n - m$, calculated for typical experimental parameters (see text).

with $a_{n,q}(k)$ being the Fourier coefficients of the Bloch functions and $|k\rangle$ the plane wave state. These functions can be constructed using the periodic solutions of the Mathieu differential equation [17, 18] with their phase chosen such that the resulting Wannier states are real and have the proper parity corresponding to their respective vibrational levels [13]. The coefficients $a_{n,q}(k)$ are numerically obtained from algorithms for the computation of Mathieu coefficients [19]. Inserting (6) in (3) and taking into account the parity of the Wannier states, or equivalently the parity of the band n , one eventually arrives at the following expression for the Franck-Condon factors

$$I_{n,r}^{n',r'}(\Delta x) = 2 \sum_{k \in \text{BZ}} \sum_{q \in \mathbb{Z}} \mathcal{F} \left[\left(k + \frac{2\pi}{d} q \right) (\Delta x + r - r') \right] a_{n,q}^*(k) a_{n',q}(k), \quad (7)$$

where we have defined $\mathcal{F}(x) := \cos(x)$ if n and n' have the same parity, and $\mathcal{F}(x) := \sin(x)$ otherwise. Numerical evaluation of (7) is shown in figure (2).

Considering a single lattice site and assuming the harmonic approximation for the potential, the shift operator takes the simple form $\hat{T}_{\Delta x} = \exp[\eta_x(a^\dagger - a)]$, where a^\dagger (a) is the raising (lowering) operator acting on the vibrational states. Here we introduced the spatial Lamb-Dicke parameter

$$\eta_x = \Delta x / (2x_0), \quad (8)$$

where x_0 is equal to the rms width of the motional ground state. When $\eta_x \ll 1$, taking the first order term in η_x of $\hat{T}_{\Delta x}$ allows for a simple expression of the Franck-Condon factors for transitions on the same lattice site (i.e., $r=r'=0$), $I_{n,0}^{n',0}(\Delta x) \approx \delta_{n,n'} + \eta_x(\sqrt{n'}\delta_{n',n+1} - \sqrt{n}\delta_{n',n-1})$.

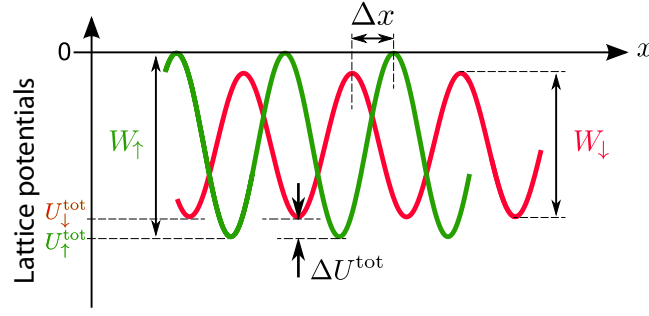


Figure 3: State-dependent optical lattices relatively shifted by a distance Δx . The total trap depth difference $\Delta U^{\text{tot}} = U_{\uparrow}^{\text{tot}} - U_{\downarrow}^{\text{tot}}$, and lattice contrast W_s for spin state $|s\rangle$ are shown. Unlike the spin $|\uparrow\rangle$ lattice, the contrast and total depth of the spin $|\downarrow\rangle$ lattice vary with the shift distance.

2.2. Experimental setup

We load Cesium (^{133}Cs) atoms from a magneto optical trap into a 1D optical lattice formed by two counter-propagating, far-detuned, linearly polarized laser beams. The filling factor is at most one atom per lattice site due to light-induced collisions [20]. A weak guiding magnetic field of 3 G oriented along the lattice lifts the degeneracy between the Zeeman sublevels of the Cesium $6^2S_{1/2}$ ground state such that atoms can be initialized by optical pumping beams into the hyperfine state $|\uparrow\rangle \equiv |F=4, m_F=4\rangle$. Microwave radiation, at around $\omega_{\text{MW}} = 2\pi \times 9.2 \text{ GHz}$, couples states $|\uparrow\rangle$ and $|\downarrow\rangle \equiv |F=3, m_F=3\rangle$ with the bare Rabi frequency of $\Omega_0 = 2\pi \times 60 \text{ kHz}$ [21]. The spin state of the atom is probed using the so called “push-out” technique [22] which consists of counting the fraction of atoms left in $|\downarrow\rangle$ after all the atoms in $|\uparrow\rangle$ have been removed by an intense radiation pulse.

An angle θ between the linear polarization vectors of the two beams forming the lattice is equivalent in the circular basis to a phase delay of 2θ between two collinear and independent circularly-polarized standing waves, σ^+ and σ^- , or equivalently to a standing wave longitudinal relative shift of

$$\Delta x_{\text{sw}}(\theta) = \theta d / \pi. \quad (9)$$

The polarization angle θ is controlled by an electro-optical modulator (EOM) and two quarter-wave plates in the path of one of the two lattice beams. The two in-phase circular components of the beam are mapped by the first $\lambda_L/4$ plate onto orthogonal linear polarizations parallel to the EOM axes. The retardation 2θ induced by the EOM is proportional to the voltage signal applied to it. The last plate then converts the linear polarizations back into the circular ones while conserving the delay.

The trapping potentials resulting from the σ^+ and σ^- standing waves for a spin state $|s\rangle$ are

$$U_s = U_s^{\text{tot}} + W_s \cos^2[k_L(x - x_s^0)] \quad (10)$$

where W_s and U_s^{tot} are the lattice contrast, taking positive values, and total trap depth for state $|s\rangle$, respectively. Both W_s and U_s^{tot} depend on the lattice lasers wavelength λ_L and on the lattice shift Δx or equivalently the polarization angle θ , see figure (3). For alkali atoms, one can define the “magic wavelength” as the one where the state $|\uparrow\rangle$ experiences the σ^+ standing wave only. This occurs at $\lambda_L = \lambda_2 + (\lambda_1 - \lambda_2)/(2\lambda_1/\lambda_2 + 1) \approx \lambda_2 + (\lambda_1 - \lambda_2)/3$, where λ_1 (λ_2) is the wavelength of the D₁ (D₂) line [23, 24], which is $\lambda_L = 866$ nm in our case. At this wavelength, for the spin $|\uparrow\rangle$ state, equation (10) reads

$$U_{\uparrow} = -W_{\uparrow} + W_{\uparrow} \cos^2(k_L x - \theta/2), \quad (11)$$

while the spin $|\downarrow\rangle$ state experiences both σ^+ and σ^- standing waves with a relative weight of 1/8 and 7/8, respectively. The lattice potential in this case is

$$U_{\downarrow} = -W_{\uparrow} + (1/8)W_{\uparrow} \cos^2(k_L x - \theta/2) + (7/8)W_{\uparrow} \cos^2(k_L x + \theta/2). \quad (12)$$

With the notation of equation (10), one finds that $W_{\uparrow} = -U_{\uparrow}^{\text{tot}}$ is independent from the angle θ , while $W_{\downarrow} = [\cos(\theta)^2 + (3/4)^2 \sin(\theta)^2]^{1/2} W_{\uparrow}$ and $U_{\downarrow}^{\text{tot}} = -(W_{\uparrow} + W_{\downarrow})/2$. In addition, one obtains the lattice relative shift $\Delta x = (d/\pi)\{\theta + \arctan[3 \tan(\theta)/4]\}/2$. Equations (11) and (12) constitute the closest realization of the idealized spin-dependent lattice discussed in section 2.1. The small admixture of a σ^+ component in equation (12) results in a lattice depth W_{\downarrow} that depends on θ , or equivalently on the lattice shift Δx , which makes the energy levels $\varepsilon_{s,n}(\Delta x)$ depend on the spin state and on the shift Δx , see figure (3). The nonlinear position shift of the U_{\downarrow} potential, x_{\downarrow}^0 , makes Δx deviate from the standing wave relative shift Δx_{sw} in equation (9), and this has to be taken into account in the calculation of the Franck-Condon factors [23].

The typical total lattice depth used in our experiment is $W_{\uparrow} \approx 850 E_R^{\text{latt}}$ (corresponding to 80 μ K), with $E_R^{\text{latt}} = \hbar^2 k_L^2 / 2m_{\text{Cs}}$ as the lattice recoil, which amounts to an oscillation frequency along the lattice axis of $\omega_{\text{vib}} \approx 2\pi \times 116$ kHz. In the transverse direction, atoms are confined only by the Gaussian profile of the lattice lasers which results in a transverse oscillation frequency of $\omega_{\text{rad}} \approx 2\pi \times 1$ kHz. The typical initial temperature of the atoms loaded into the lattice is $T \approx 10$ μ K, which in the harmonic approximation amounts to mean vibrational numbers of $\bar{n}_{\text{vib}} \approx 1.4$ and $\bar{n}_{\text{rad}} \approx 280$ in the axial and transverse directions, respectively.

2.3. Microwave sideband spectra

We investigate sideband transitions by recording microwave spectra for different lattice shifts. Controlling the relative distance Δx allows us to continuously tune the parameter η_x from 0 to about 5. In order to resolve the sidebands we use Gaussian microwave pulses with a FWHM of 30 μ s and a bare Rabi frequency of $\Omega_0/2\pi = 36$ kHz, corresponding to the π -pulse condition for the carrier transition. Figure (4) shows a combined spectrum where transitions from $n = 0$ to levels up to $n' = 14$ are well resolved [11]. Four spectra are recorded for four different lattice shifts. With an unshifted lattice only the carrier transition is visible, and it defines the zero of the microwave detuning δ_{MW} . The remaining three lattice shifts were chosen such that for each shift distance Δx the

sideband coupling strength on the same site (i.e., $r=r'$), $\Omega_{n,0}^{n',0}(\Delta x)$, is simultaneously close to maximum for a small group of adjacent sideband transitions. The coupling strength for sites $r \neq r'$ can be neglected at the given shifts.

For each shift distance Δx the microwave spectra are fitted using the spectra yielded by a numerical calculation of the time evolution based on the following Hamiltonian

$$\hat{H} = \hat{H}_0 + \hat{H}_{\text{MW}} \quad (13)$$

with

$$\hat{H}_0 = \sum_{s=\uparrow,\downarrow} \sum_n \left(\varepsilon_{s,n}(\Delta x) + \delta_{s,\uparrow} \hbar \omega_{\text{HS}} \right) |s, n, r\rangle \langle s, n, r|, \quad (14)$$

$$\hat{H}_{\text{MW}} = -\frac{\hbar}{2} \Omega_0 \sum_{r,r'} \sum_{n,n'} I_{n',r'}^{n,r}(\Delta x) \left(e^{-i\omega_{\text{MW}} t} |\uparrow, n, r\rangle \langle \downarrow, n', r'| + \text{h.c.} \right), \quad (15)$$

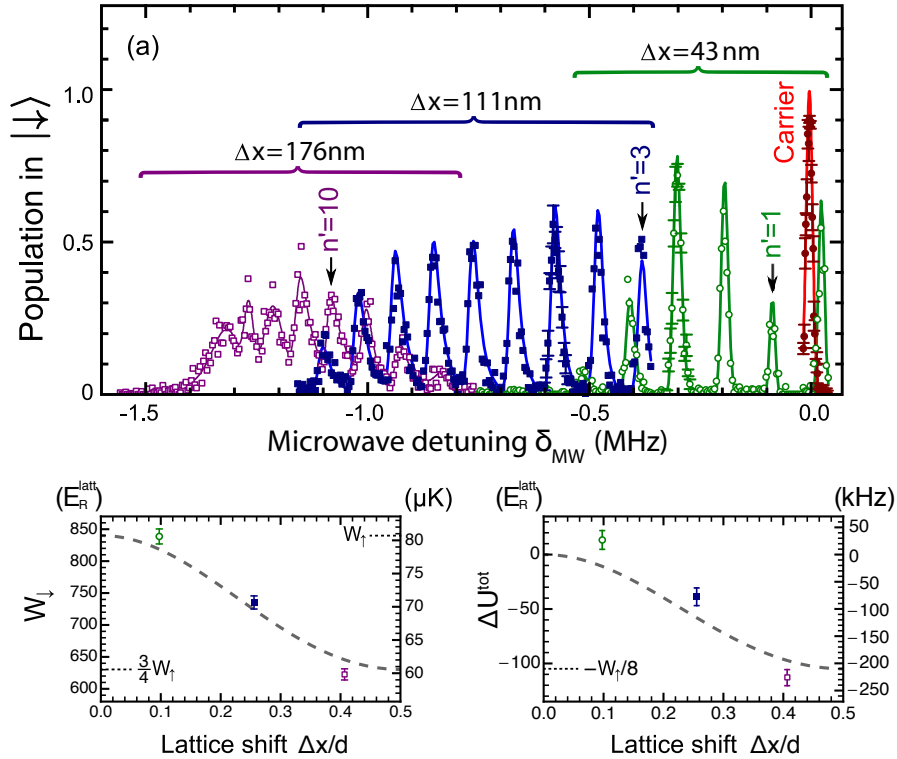


Figure 4: (a) Microwave spectrum of sideband transitions $|\uparrow, n=0\rangle \leftrightarrow |\downarrow, n'\rangle$ for lattice shifts $\Delta x = \{0\text{nm} (\bullet), 43\text{nm} (\circ), 111\text{nm} (\blacksquare), 176\text{nm} (\square)\}$ corresponding to the parameter $\eta_x = \{0, 1.2, 3.1, 4.9\}$ defined in section 3.1 (data points from [11]). The microwave detuning is given with respect to the carrier transition frequency. Data points are the average on about 100 atoms and they are here fitted with a model that takes into account broadening mechanisms detailed in the text. The error bars, reported only for three representative peaks, are obtained with the 68% Clopper-Pearson interval method for binomial statistics. The panels (b) and (c) compare the expected values (dashed lines) for the lattice contrast W_\downarrow and total trap depth difference ΔU^{tot} (see figure (3) and text in section 2.2) with the values extracted from the fits (1% uncertainty).

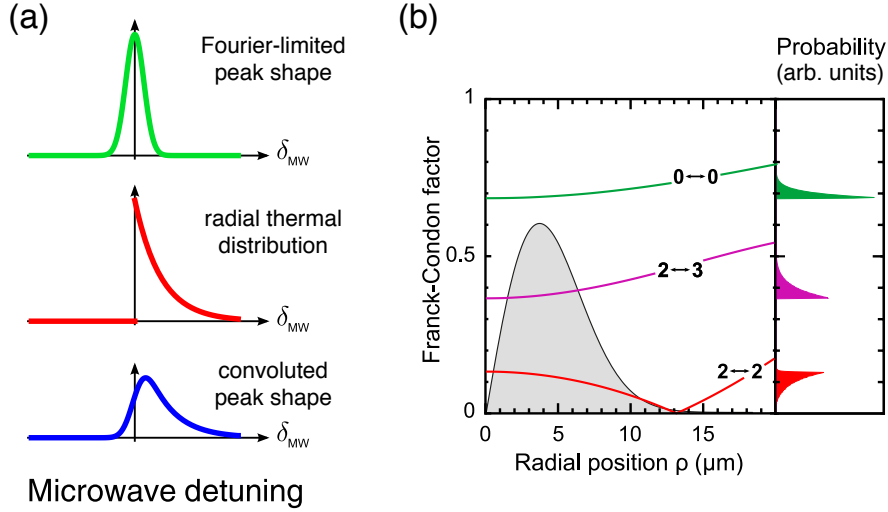


Figure 5: (a) Inhomogeneous broadening effect due to the transverse motion of the atoms in the trap. The overall peak profile (bottom curve) is the convolution of the other two profiles. The Fourier-limited FWHM and the thermal broadening are typically 20 kHz and 5 kHz (for $T_{2D} \sim 10 \mu\text{K}$ and first sideband), respectively. (b) Left panel: Franck-Condon factors as a function of the radial distance ρ (here, $\theta = 15^\circ$). The gray profile shows the 2D radial distribution from equation (16) for the same temperature. Right panel: Resulting thermal distribution of Franck-Condon factors.

where ω_{HS} denotes the hyperfine splitting frequency of the ground state. With this notation, the microwave detuning reads $\delta_{\text{MW}} = \omega_{\text{MW}} - \omega_{\text{HS}}$.

Given the deep lattice regime considered here, in the numerical solution of equation (13) the maximum number of vibrational levels per site can be restricted with a good approximation to $n_{\text{max}} = 15$, before atoms start to behave like free particles tunneling between sites or directly coupling to the continuum. In this regime, the coupling strength for a sideband transition between two lattice sites separated by a distance $x > d$ are two orders of magnitude lower than the typical time scales of our experiment; therefore, we limit the site indices to $r = r'$.

In the fitting of the sideband spectra, the energy levels $\varepsilon_{s,n}$ and Franck-Condon factors $I_{n,0}^{n',0}$ depend on the fitting parameters Δx , U_s^{tot} and W_s . In particular, in the harmonic approximation the spacing between two adjacent peaks is equal to the trap frequency of the U_\downarrow potential, which therefore determines the lattice contrast W_\downarrow ; the absolute offset of each spectrum is mainly determined by the difference of the total trap depths, $\Delta U^{\text{tot}} = U_\uparrow^{\text{tot}} - U_\downarrow^{\text{tot}}$, expressed in frequency units. Additionally, an average over the thermal motion of the atoms in the transverse direction of the one-dimensional optical lattice has to be performed. In fact, the lattice parameters U_s^{tot} and W_s depend on the transverse position of the atom, and to take this dependence into account we assume that during the microwave dynamics an atom has a “frozen” transverse position ρ . This assumption is justified by the slow transverse motion of the atoms, $\omega_{\text{rad}}/2\pi \approx 1 \text{ kHz}$, compared to the lowest bare Rabi frequency used for the microwave

pulse, $\Omega_0/2\pi \approx 14$ kHz. The transverse positions of the atoms are then assumed to be distributed according to a two-dimensional Boltzmann distribution, shown in figure (5b) and given in the harmonic approximation by

$$\mathcal{P}(\rho) = \frac{\rho}{\sigma^2} \exp\left(-\frac{\rho^2}{2\sigma^2}\right), \quad \text{with} \quad \sigma = \sqrt{\frac{k_B T_{2D}}{m_{\text{Cs}} \omega_{\text{rad}}^2}} \quad (16)$$

with T_{2D} the transverse temperature. The thermal transverse position distribution results in an inhomogeneous distribution of microwave sideband resonance frequencies and of Franck-Condon factors, shown qualitatively in figure (5). Both distributions are used to weight the calculated spectra, with T_{2D} as an additional fitting parameter. The figure shows that thermal broadening effect becomes larger for higher sidebands, exhibiting a more pronounced asymmetric peak shapes. This behavior has a clear explanation: in the harmonic approximation, for instance, one expects the thermal broadening to increase linearly with band index n while the Fourier-limited FWHM remains constant.

The best-fit results for W_{\downarrow} and ΔU^{tot} are shown in figures (4b) and (4c). This method allows us to spectroscopically determine the parameters of the spin-dependent potentials seen by the atoms with a relative uncertainty of about 1%. The small deviations from the expected values (dashed curves in the figure) can be attributed in part to measurement uncertainty and to polarization imperfections in the standing wave beams, resulting in slightly distorted potentials. For instance, polarization distortion can be responsible for the non monotonic behavior of the data points in figure (4c). From the fit, we obtain a temperature of $T_{2D} = (2.7 \pm 0.5) \mu\text{K}$. Without axial ground state cooling, we measure a three-dimensional temperature of $10 \mu\text{K}$ by means of the adiabatic lowering technique [25]. This discrepancy requires further investigations.

3. Microwave sideband cooling

The general principle of resolved sideband cooling, depicted in figure (6), relies on the repetition of cooling cycles where each cycle starts by a sideband transition $|\uparrow, n\rangle \rightarrow |\downarrow, n-1\rangle$ removing a vibrational energy quantum $\hbar\omega_{\text{vib}}$. The cycle is then closed by an optical repumping process with a transition to an optically excited state $|e\rangle$ followed by a spontaneous decay to the initial spin state. Because of the optical repumping, the motional energy of the atom in each cycle increases on average, which corresponds to heating. Therefore, in order to achieve cooling the overall energy gained by an atom after one cycle must be negative. In general, heating is caused by the momentum recoil from the optical repumping photons, i.e. recoil heating. In the microwave-based scheme however, shown in figure (6b), an additional source of heating, called hereafter “projection heating,” is present. It is due to the difference between the trapping potentials of the internal states, in this case it is a spatial shift. This difference makes the projection of a vibrational state $|\downarrow, n\rangle$ on an arbitrary state $|\uparrow, m\rangle$ appreciable in contrast to the case of identical potentials where transitions beyond $m = n, n \pm 1$ are

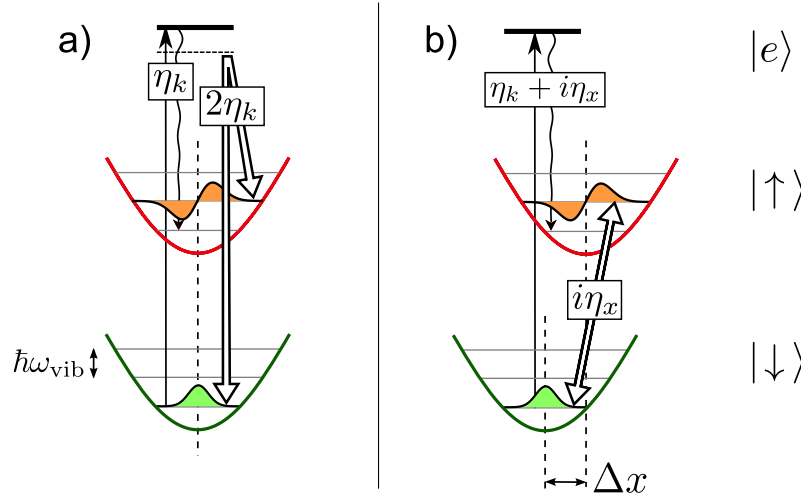


Figure 6: (a) Raman sideband cooling scheme: a two-photon Raman transition between two identical trapping potentials reduces the vibrational state, $|\uparrow, n\rangle \rightarrow |\downarrow, n-1\rangle$. The wavefunction is shifted in momentum space by $\hbar\Delta k$. (b) Microwave sideband cooling scheme: a microwave transition between two shifted trapping potentials reduces the vibrational state. Note that we use here a blue sideband transition to reduce the vibrational state, instead of the typical usage of a red sideband transition [7].

negligible.

3.1. Raman vs. microwave sideband cooling

In the standard Raman-based sideband cooling schemes [6, 26] the sideband is induced by a two-photon transition where the coupling is given by the matrix element

$$\Omega_{n-1,n}^{\text{Raman}} = \langle \downarrow, n-1 | \hat{T}_{\Delta k} | \uparrow, n \rangle \times \Omega_0^{\text{Raman}}, \quad (17)$$

where $\hat{T}_{\Delta k} \equiv \exp(i\hat{x}\Delta k)$ is the momentum shift operator and $\Delta k \approx 2k_{\text{opt}}$ is the wavevector difference between the two optical photons for counterpropagating beams. From here on, it is understood that all transitions occur on the same site, $r = r'$. In the microwave-based scheme we neglect the microwave photon recoil, and the sideband coupling corresponding to a lattice shift Δx between nearest neighboring sites is then given by

$$\Omega_{n-1,n} = \langle \downarrow, n-1 | \hat{T}_{\Delta x} | \uparrow, n \rangle \times \Omega_0. \quad (18)$$

Using the harmonic approximation, the Raman and microwave sideband couplings can be expanded to the first order in the parameters $\eta_k = \hbar k_{\text{opt}}/(2p_0)$ and $\eta_x = \Delta x/(2x_0)$, as shown in table (1), where $p_0 = \sqrt{m_{\text{Cs}}\hbar\omega_{\text{vib}}/2}$ and $x_0 = \sqrt{\hbar/(2m_{\text{Cs}}\omega_{\text{vib}})}$ are the momentum and spatial rms width of the ground-state wavefunction, respectively [27]. From table (1) we can note a clear duality between momentum and spatial shifts in the two sideband cooling methods. The duality is better emphasized by using the general complex Lamb-Dicke parameter

$$\eta = \eta_k + i\eta_x = \hbar k_{\text{opt}}/(2p_0) + i\Delta x/(2x_0) = k_{\text{opt}}x_0 + ip_0\Delta x/\hbar, \quad (19)$$

Table 1: Raman vs. microwave sideband cooling in the harmonic approximation. The sideband couplings are first-order expansions in η_k and η_x in the Lamb-Dicke regime defined by $|\eta| = |\eta_k + i\eta_x| \ll 1$, under the harmonic approximation.

	Raman	Microwave
Sideband coupling strength $\Omega_{n-1,n}/\Omega_0$	$i2\eta_k\sqrt{n}$	$-\eta_x\sqrt{n}$
Recoil heating per cycle	$2\hbar\omega_{\text{vib}}\eta_k^2$	$2\hbar\omega_{\text{vib}}\eta_k^2$
Projection heating per cycle	—	$\hbar\omega_{\text{vib}}\eta_x^2$
Overall heating per cycle	$2\hbar\omega_{\text{vib}}\eta_k^2$	$\hbar\omega_{\text{vib}}(\eta_x^2 + 2\eta_k^2)$

which accounts for both degrees of freedom via the momentum and spatial Lamb-Dicke parameters, η_k and η_x , respectively. This generalized approach was introduced first in ion systems to describe microwave-induced sidebands in the presence of spin-dependent forces [14].

In the Raman-based cooling schemes with identical trapping potentials, the spatial Lamb-Dicke parameter η_x vanishes and the heating comes from the recoil of the optical repumping photons, as depicted in the figure (6a). In the microwave-based scheme however, the generalized Lamb-Dicke parameter is complex and the heating is caused by a combination of recoil and projection heating.

The energy gained by an atom from recoil heating after one cycle results from two recoils, one from absorption and one from spontaneous emission, and is therefore given by

$$\Delta E_{\text{rec}} = 2E_{\text{R}}, \quad (20)$$

where $E_{\text{R}} = \hbar^2 k_{\text{opt}}^2 / 2m_{\text{Cs}}$ is the optical photon recoil energy [28]. This quantity does not depend on the details of the potentials but only on the atom's properties, and it expresses the overall three-dimensional recoil heating.

In the shifted potentials shown in figure (6b), in addition to the recoil heating, the atom's motional energy increases on average by the projection heating energy ΔE_{proj} . This is due to the non-vanishing projection of the atom's initial vibrational state $|\downarrow, n\rangle$ onto the vibrational basis $|\uparrow, m\rangle$ of the final spin state in the optical repumping process. In the harmonic approximation, with $H_{\text{ext}} = \hbar\omega_{\text{vib}}(n+1/2)$, and after adiabatic elimination of the excited state $|e\rangle$, the projection heating contribution for a relative shift Δx can be derived as

$$\begin{aligned}
\Delta E_{\text{proj}} &= \hbar\omega_{\text{vib}} \sum_m (m-n) \left| \langle m | \hat{T}_{\Delta x} | n \rangle \right|^2 = \\
&= \sum_m \langle m | [\hat{H} \hat{T}_{\Delta x} - \hat{T}_{\Delta x} \hat{H}] | n \rangle \langle n | \hat{T}_{\Delta x}^\dagger | m \rangle = \\
&= \langle n | (\hat{H}_{\text{ext}}(\Delta x) - \hat{H}_{\text{ext}}) | n \rangle, \quad (21)
\end{aligned}$$

where we have introduced the shifted Hamiltonian

$$\hat{H}_{\text{ext}}(\Delta x) = \hat{T}_{\Delta x}^\dagger \hat{H}_{\text{ext}} \hat{T}_{\Delta x} = \frac{\hat{p}^2}{2m_{\text{Cs}}} + \frac{1}{2}m_{\text{Cs}}\omega_{\text{vib}}^2(\hat{x} + \Delta x)^2. \quad (22)$$

The result of equation (21) applies in general for any potential profile, and in the harmonic approximation it results in a quantity which is independent of n ,

$$\Delta E_{\text{proj}} = \frac{1}{2}m_{\text{Cs}}\omega_{\text{vib}}^2\Delta x^2, \quad (23)$$

which is nothing but the potential energy difference as expected from the semi-classical picture in figure (1).

Using the same method, one can generally show that in the microwave sideband cooling scheme the total average heating energy gained by an atom in one cooling cycle is the sum of the recoil and projection contributions. The total energy balance per cycle then becomes

$$\Delta E_{\text{tot}} = \Delta E_{\text{proj}} + \Delta E_{\text{rec}} - \hbar\omega_{\text{vib}} = \hbar\omega_{\text{vib}}(\eta_x^2 + 2\eta_k^2 - 1). \quad (24)$$

Similarly to the usual definition of the Lamb-Dicke regime [29], the condition for cooling $\Delta E_{\text{tot}} < 0$ defines a generalized Lamb-Dicke regime as the range where $|\eta| < 1$.

3.2. Quantitative model based on master equation

The general theory of sideband cooling is very well known and has been extensively studied in the literature [5, 27, 30, 31]. Here, we discuss a quantitative model based on the Lindblad master equation formalism. To provide a concrete example, we apply the model to the level scheme of our specific system, though the model can be adapted to other similar systems.

In the cooling cycle depicted in figure (7), microwave radiation resonant with the first blue sideband transfers atoms from states $|\uparrow, n\rangle$ to states $|\downarrow, n-1\rangle$. Concurrent with the microwave, a σ^+ -polarized repumper laser beam couples state $|\downarrow\rangle$ to state $|6^2P_{3/2}, F' = 4\rangle \equiv |e\rangle$, from where the atoms close the cooling cycle by spontaneously decaying back to state $|\uparrow\rangle$. Due to the appreciable probability of atoms decaying from state $|e\rangle$ to state $|F = 4, m_F = 3\rangle \equiv |a\rangle$, a second equally polarized pumping laser couples the two states and brings the atoms which have decayed to state $|a\rangle$ back into the cooling cycle. In each cycle, an atom loses energy on average until it reaches the “dark state” $|\uparrow, n=0\rangle$ where it is no longer affected by the microwave or the repumping lasers. Nevertheless, a small probability remains that the dark state is depopulated due to photon scattering from the lattice lasers or an off-resonant microwave carrier transition.

To describe the cooling dynamics, we reduce the problem at hand to an effective model with three spin states with the set of motional states associated with each one of them. The considered Hilbert space is then the one spanned by the states $|s, n\rangle$, with n being the vibrational level and $|s\rangle$ being one of the three internal states $|\uparrow\rangle, |\downarrow\rangle$ or $|a\rangle$. The optically excited state $|e\rangle$ is adiabatically eliminated due to its very short lifetime,

$\tau = 30$ ns, compared to the motional time scale. We use the Lindblad master equation formalism to write the time evolution of the effective model's density matrix as [31]

$$\frac{d\rho}{dt} = -\frac{i}{\hbar}[\hat{H}'_0 + \hat{H}_{\text{MW}}, \rho] + \mathcal{L}[\rho], \quad (25)$$

where \hat{H}'_0 is the extension of the Hamiltonian from equation (14) to the states $|a, n\rangle$

$$\hat{H}'_0 = \sum_{s=\{\uparrow, \downarrow, a\}} \sum_n \varepsilon_{s,n}(\Delta x) |s, n, r\rangle \langle s, n, r|, \quad (26)$$

and \mathcal{L} is the Lindblad superoperator with the projectors

$$L_{n,r,s}^{n',r',s'} = |s, n, r\rangle \langle s', n', r'|, \quad (27)$$

and the effective decay rates $\gamma_{s,n,r}^{s',n',r'}$ for the transitions $|s', n', r'\rangle \rightarrow |s, n, r\rangle$ which are given by

$$\gamma_{s,n,r}^{s',n',r'} = \alpha_s R_{s'} \left\langle |M_{s,n,r}^{s',n',r'}|^2 \right\rangle_{\vec{k}_{\text{sp}}}, \quad (28)$$

with

$$M_{s,n,r}^{s',n',r'} = \langle n, r, s | \hat{T}_{\Delta k_{s,s'}} \hat{T}_{\Delta x} | s', n', r' \rangle. \quad (29)$$

Here, α_s is the branching ratio for the spontaneous emission from state $|e\rangle$ to state $|s\rangle$, and R_a, R_\downarrow are the pumping and repumping rate, respectively, as shown in figure (7). In addition, we account for the possibility that an atom in $|\uparrow\rangle$ state scatters a photon from the lattice with the rate R_\uparrow . The matrix element $M_{s,n,r}^{s',n',r'}$ accounts for the relative spatial shift between the two involved vibrational states and for the transferred momentum of both optical photons $\Delta k_{s,s'} = k_{\text{opt}} + \vec{k}_{\text{sp}} \cdot \vec{e}_x$ in the optical repumping process, with

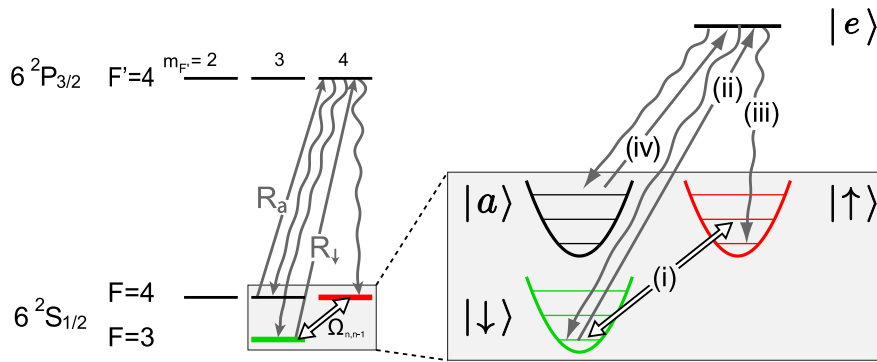


Figure 7: Microwave sideband cooling scheme in a realistic physical system using ^{133}Cs atoms. (i) Microwave radiation tuned to the first blue sideband induces a $|\uparrow, n\rangle \rightarrow |\downarrow, n-1\rangle$ transition decreasing the motional quantum number by one. (ii) The cooling cycle is closed by an optical repumping transition $|\downarrow\rangle \rightarrow |F'=4\rangle$, with rate R_\downarrow , and (iii) a spontaneous decay back to state $|\uparrow\rangle$. In (iv) an additional pumping laser brings the atoms which have decayed to state $|a\rangle$ back into the cooling cycle, with rate R_a . Atoms reaching the dark state $|\uparrow, n=0\rangle$ are out of the cooling cycle unless off-resonantly excited or heated externally.

\vec{k}_{sp} being the wavevector of the spontaneously emitted photon and \vec{e}_x being the unit vector along the lattice direction. Additionally, one has to perform an average over \vec{k}_{sp} , indicated by the angle brackets in equation (28) .

Given our experimental parameters, we compute the steady-state solution to equation (25) numerically, using the same approximations as in section 2.3. In the computation, the microwave is resonant with the $|\uparrow, 1\rangle \rightarrow |\downarrow, 0\rangle$ transition. The rates R_a and R_\downarrow are set by the experimental values, which are chosen comparable to $\Omega_{0,1}$ and smaller than the vibrational level separations to avoid off-resonant transitions by power broadening of the vibrational levels of the $F = 3$ ground state. Figure (8) shows a contour plot of the ground state population $P_{|n=0\rangle} \equiv \sum_{s,r} P_{|s,0,r\rangle}$ in the steady state as a function of the bare microwave Rabi frequency and the relative shift distance expressed in terms of η_x . When projection heating dominates, $\eta_x \gtrsim \eta_k$, the energy balance in equation (24) just requires $\eta_x < 1$ for cooling; for instance, figure (8) shows that a ground state population $P_{|0\rangle} > 80\%$ can be reached with $\eta_x < 0.8$. For very small lattice shifts however, with $\eta_x \ll 1$, the microwave coupling for the blue sideband transition becomes small compared to that of the carrier transition, which renders the microwave action of removing an energy $\hbar\omega_{\text{vib}}$ per cycle inefficient compared to the recoil heating, which is the dominant heating source for such small shifts. Weak microwave sideband coupling and hence inefficient microwave cooling will also be present at very low bare Rabi frequency, namely at the Rabi frequencies where the sideband coupling becomes lower than the rate of depopulation of the dark state. For high Rabi frequencies of the same order of magnitude as the vibrational level spacing, the carrier coupling becomes comparable to the blue sideband coupling, and the microwave cooling action is again reduced.

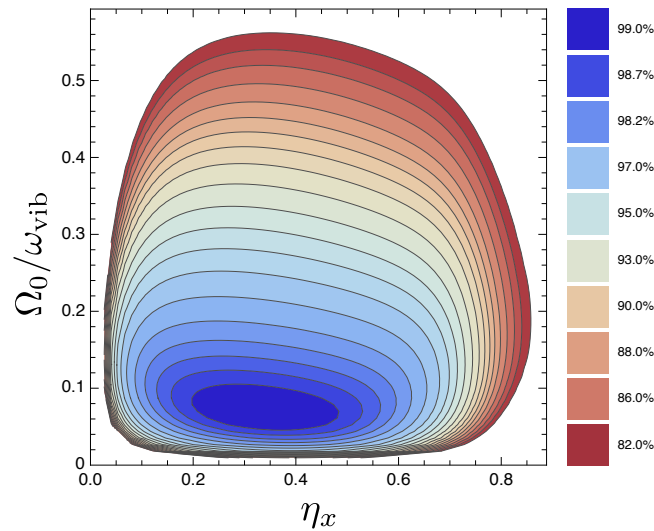


Figure 8: Steady state population in the motional ground state $P_{|n=0\rangle}$ as a function of η_x and the bare microwave Rabi frequency Ω_0 .

3.3. Experimental results

Microwave cooling is obtained by applying microwave radiation on resonance with the first blue sideband, $|\uparrow, 1\rangle \rightarrow |\downarrow, 0\rangle$, for a certain duration τ_{cooling} , at a certain lattice shift Δx , concurrently with the two optical pumping lasers as shown in figure (7). In order to probe the final vibrational state distribution, we record a spectrum of the first order sideband transitions using a Gaussian microwave pulse satisfying the π -pulse condition for the first red sideband, figure (9a). In the low temperature limit, the height of the first blue sideband peak provides a good measure of the motional ground state population, $P_{|\uparrow,0\rangle}$, and thus of the cooling efficiency. For instance, for atoms in the ground state one expects to detect no blue sideband. Figures (9a) and (9b) show two microwave spectra recorded before and after cooling, clearly indicating a reduction of temperature by the cooling process.

In order to determine the optimum cooling parameters, the blue sideband height is remeasured while scanning different variables, namely the optical pumping intensities, the cooling microwave power and frequency, the lattice shift distance and the duration of the cooling pulse. Figure (9c) shows a scan of the cooling microwave frequency. As indicated by a nearly zero detected signal from the blue sideband, the optimum frequency for cooling lies evidently in the vicinity of the first blue sideband, while a less pronounced cooling is also present at the position of the second blue sideband. Furthermore, the measurement reveals the absence of the blue sideband signal in a broad range extending to negative detunings in addition to a weak dip at the position of the carrier. These two observations are correlated with a decrease in the atom survival given in the same figure. This shows that, instead of being due to cooling, the absence of the blue sideband here is due to increased atom losses. In fact, for zero and negative microwave detunings, that is if the microwave is resonant with the carrier $|\uparrow, n\rangle \rightarrow |\downarrow, n\rangle$ or red sideband $|\uparrow, n\rangle \rightarrow |\downarrow, n+m\rangle$ transitions respectively, the energy of the atom increases on average in each cooling cycle. In the case of zero detuning the increase is due mainly to recoil and projection heating in the absence of microwave cooling, while for negative detunings microwave sideband heating occurs in addition to the recoil and projection heating.

Once the optimum cooling parameters have been determined, we extract the achieved steady state temperature assuming a thermal Boltzmann distribution and neglecting the anharmonic spacing of the vibrational levels. The ratio between the red and blue sideband heights is proportional to the Boltzmann factor which is related to the average motional quantum number $\langle n \rangle$ by

$$\frac{P_{\uparrow,1}}{P_{\uparrow,0}} = \exp\left(-\frac{\hbar\omega_x}{k_B T}\right) = \frac{\langle n \rangle}{\langle n \rangle + 1} \quad (30)$$

Using the fitted sideband heights from figure (9b), we calculate $\langle n \rangle = 0.03 \pm 0.01$, and a ground state population of $P_{\uparrow,0} \simeq 97\%$, corresponding to a temperature $T \simeq 1.6 \mu\text{K}$. Table (2) summarizes the optimum cooling parameters for our setup.

Table 2: Optimal microwave cooling parameters for $\omega_{\text{vib}} = 2\pi \times 116$ kHz.

$\Omega_0/2\pi$	η_x	η_k	R_{\downarrow}	R_a	R_{\uparrow}	τ_{cooling}
16 kHz	0.3	0.1	35 ms^{-1}	35 ms^{-1}	15 s^{-1}	20 ms

4. Motional state control

4.1. Motional state detection

We have developed a vibrational state detection scheme which allows us to determine the vibrational state distribution of any given motional state. It relies on removing all atoms above a selected vibrational state n from the trap and counting the remaining atoms, as illustrated in figure (10a). The distribution is then reconstructed from the differences of subsequent measurements.

Atoms are first transferred to state $|\downarrow\rangle$ by means of an adiabatic passage microwave pulse that is resonant with the carrier transition in unshifted lattices, which preserves vibrational states' populations. A microwave pulse resonant with the red sideband $|\downarrow, n\rangle \rightarrow |\uparrow, 0\rangle$ transfers atoms from states $|\downarrow, m\rangle$ with $m \geq n$ to states $|\uparrow, m - n\rangle$. The transferred atoms are eventually pushed out of the trap (see section 2.2). However, since the sideband transition rates depend on the initial vibrational state $|\downarrow, n\rangle$ (due to, e.g., trap anharmonicity and Franck-Condon factor differences) the microwave pulse does not achieve full transfer efficiency for all transitions. To overcome this limitation, the procedure of microwave pulse plus push-out is repeated several times to deplete all vibrational states $|\downarrow, m\rangle$ with $m \geq n$. If f is the population transfer efficiency for a given n , then after N repetitions the effective population transfer efficiency becomes $f' = 1 - (1 - f)^N$. For instance, an initial efficiency of $f = 70\%$ is thus increased to $f' \sim 97\%$ with $N = 3$ repetitions. Measuring the fraction of remaining atoms as a function of the microwave frequency, we obtain a sequence of plateaus at the successive

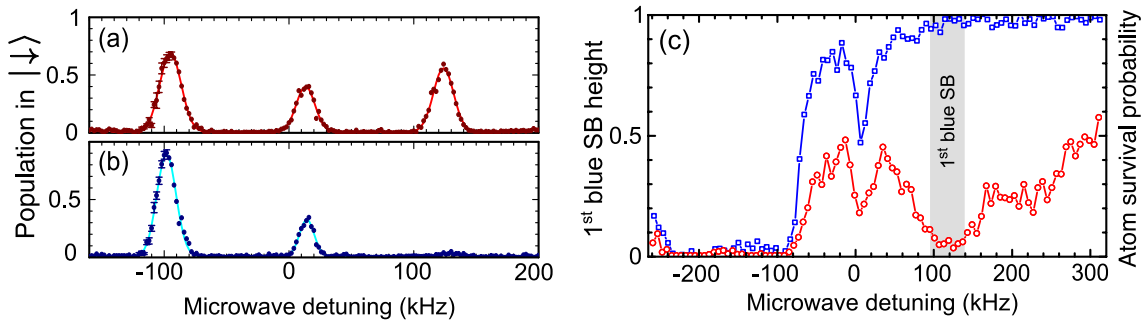


Figure 9: Microwave spectroscopy performed (a) before cooling and (b) after 20 ms of microwave cooling, with optimal experimental parameters (see Table 2). (c) Blue sideband height vs. detuning of the microwave cooling frequency (\circ) and atom survival probability measured after the cooling (\square), (data points in (a) and (b) are from [11]).

sideband frequencies, as shown in figure (10b). The plateau corresponding to the n^{th} sideband indicates the integrated population of states $m < n$, that is, the cumulative distribution function $F_n = \sum_{m=0}^{n-1} p_m$, from which the individual populations of the vibrational states are then derived.

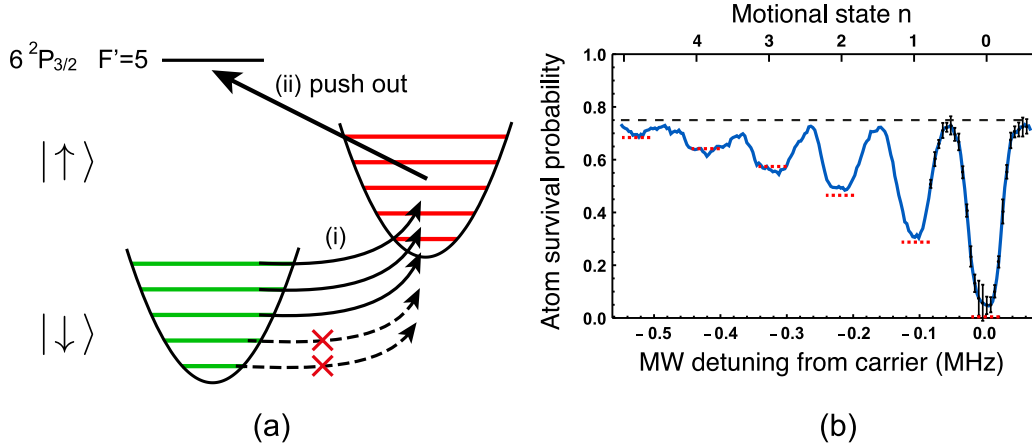


Figure 10: (a) Method for measuring vibrational state population distributions: (i) an initial microwave pulse resonant with the n^{th} red sideband transfers all atoms in states $|\downarrow, m\rangle$, with $m \geq n$, to state $|\uparrow\rangle$; (ii) the transferred atoms are pushed out of the lattice; (i) and (ii) are repeated N times to overcome low pulse efficiency. (b) Surviving fraction of atoms for a thermal state, with the dotted lines indicating a thermal distribution of $T \approx 11.6 \mu\text{K}$; this temperature is compatible with the independently measured one of about $10 \mu\text{K}$. For each sideband n , after $N = 3$ repetitions of the microwave pulse plus push-out, only the atoms in states $m < n$ survive. The horizontal dashed line indicates the maximum survival probability, limited by the off-resonant transitions during the repeated pulses. For the sake of clarity, error bars have been displayed for the carrier transition only.

4.2. Motional state engineering

With 97% of the atoms cooled to state $|\uparrow, n = 0\rangle$ (see section 3.3), controlled preparation of different motional states is possible using a combination of microwave pulses and selected lattice shifts.

The simplest state that can be prepared is the Fock state $|\downarrow, m\rangle$. It requires addressing the m -th red sideband transition at the lattice shift Δx chosen to maximize the coupling $|\uparrow, 0\rangle \leftrightarrow |\downarrow, m\rangle$. The fidelity for preparing this state is limited by the cooling efficiency, the population transfer efficiency and the selectivity of the microwave pulse. Using an adiabatic passage pulse [32], a state preparation fidelity close to 98% has been achieved for states up to $m = 6$.

A superposition of two Fock states is created by a two-pulse sequence as shown in the inset of figure (11b). An initial microwave pulse resonant with the transition

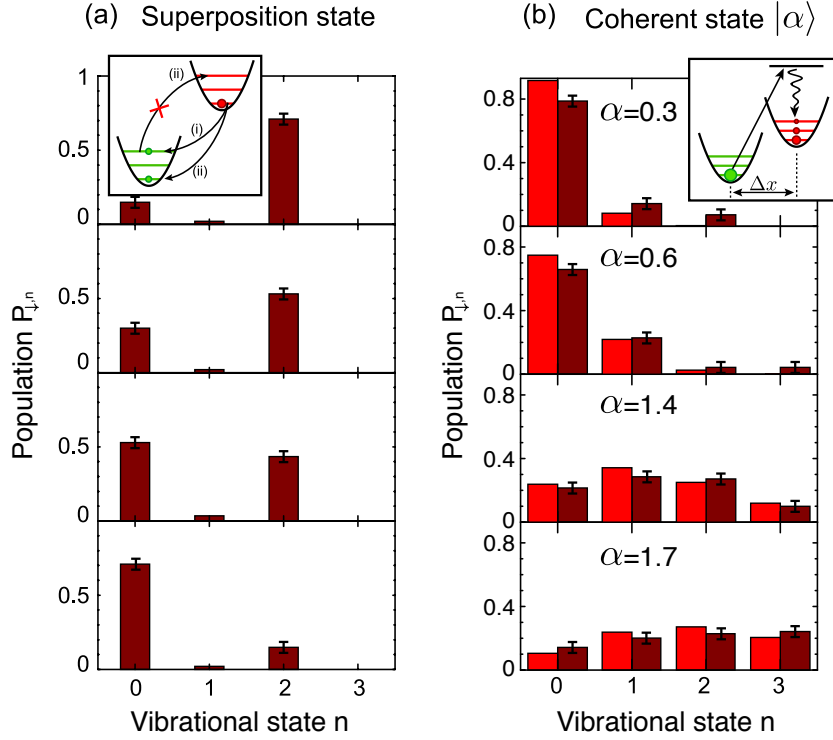


Figure 11: Motional state preparation and analysis. Shown are the populations of the vibrational states $n = 0, \dots, 3$ after (a) creating superposition states of $|n = 0\rangle$ and $|n = 2\rangle$ with different weights (from top to bottom, area of the first MW pulse 0.30, 0.40, 0.55, 0.70 in units of π) and (b) coherent vibrational states for different amplitudes α , where the left bars (brighter red) indicate the theoretically expected populations. The analysis technique used here, see figure (10a), can only measure vibrational states' populations but not coherences.

$|\uparrow, 0\rangle \rightarrow |\downarrow, 2\rangle$, performed at the lattice shift which maximizes the coupling for the transition, generates the state

$$|\psi\rangle = c_{\uparrow,0} |\uparrow, 0\rangle + c_{\downarrow,2} |\downarrow, 2\rangle \quad (31)$$

with variable coefficients $c_{\uparrow,0}$ and $c_{\downarrow,2}$ determined by the pulse duration. The lattice shift Δx is then changed to the distance at which the Franck-Condon factor for the transition $|\uparrow, 2\rangle \leftrightarrow |\downarrow, 2\rangle$ is zero. The shifting is precisely timed so that the probability of changing the vibrational state by the acceleration of the lattices is zero [33]. At the new lattice shift, a second microwave pulse resonant with the carrier transition maps the population $|c_{\uparrow,0}|^2$ onto $|\downarrow, 0\rangle$. One would expect as a result a coherent superposition between $|\downarrow, 0\rangle$ and $|\downarrow, 2\rangle$. However, because of the appreciable duration of the sequence of 320 μs (two sideband-resolved pulses plus lattice shift operation) compared to the total spin coherence time of $\sim 250 \mu\text{s}$ in our setup, the coherence between the two vibrational states is partially lost during the preparation procedure. This is a technical limitation which can be overcome by improving the coherence time, for instance in our setup, by cooling the transverse motion of the atoms to the three-dimensional ground state [34].

This scheme represents a relevant step towards the use of the vibrational state as the physical carrier for a qubit and/or the preparation of arbitrary motional superposition states when working with neutral atoms.

In the same vein of engineering motional states, we project the state $|\downarrow, n=0\rangle$ onto a shifted potential to create the state

$$|\alpha\rangle = \hat{T}_{\Delta x} |\uparrow, n=0\rangle = e^{\alpha a^\dagger - \alpha^* a} |\uparrow, n=0\rangle \quad (32)$$

with $\alpha = \eta_x$. We realize this by applying an optical repumping pulse while the lattice is displaced by Δx . This corresponds to exciting the transition $|\downarrow\rangle \rightarrow |e\rangle$ followed by a spontaneous decay to state $|\uparrow\rangle$, which occur on a time scale much shorter than the oscillation period of the atom in the trap. We also neglect the recoil transferred by the optical repumping photons, which is equivalent to assuming $\eta_k = 0$. Because the decay process additionally involves transitions to states $|a\rangle$ and $|\downarrow\rangle$, the resulting state is a statistical mixture of the three internal states; our analysis scheme however measures the vibrational population of the state projected on $|\uparrow\rangle$ state shown in equation (32). The statistical mixture can be avoided by replacing the optical repumping pulse and spontaneous decay by a fast two-photon Raman transition. Measuring the population distribution of the created state reveals a clear agreement with the theoretical expectation, as shown in figure (11b). With the state detection scheme presented in section 4.1, so far we can only measure populations, while coherences could be accessed in the future through interferometric schemes.

5. Conclusions and outlook

We have shown that microwave sideband transitions in spin-dependent optical lattices are a favorable alternative to Raman transitions for sideband cooling and motional state engineering. The effective Lamb-Dicke parameter can be continuously adjusted from zero to above one, giving the possibility to address directly higher-order sideband with coupling frequencies comparable to the bare Rabi frequency. We investigated the performance of microwave sideband cooling in the generalized Lamb-Dicke regime, and we compared it to the Raman sideband cooling; our analysis can be easily extended to the three-dimensional case [15].

Quantum engineering of motional states represents one of the most attractive uses of microwave-induced sidebands. We demonstrated here a first step towards the creation of superposition between Fock states, and the preparation of coherent states. In the future, the interest resides in proving the coherence properties of these states through interferometric schemes, for instance, by measuring the accumulated phase between two distinct Fock states, or through quantum beat experiments [35].

Along the same line, spin-dependent shift operations can be employed to transfer a state-dependent momentum kick, allowing the realization of a superposition of opposite coherent states, producing Schrödinger-cat-like states as has been realized with ions [36].

Microwave control of atomic motion in a spin-dependent optical lattice can be of interest for storing and processing quantum information via the motional states [37]. For

instance, the strength of coherent collisions for atoms close to the motional ground state exhibits a marked dependence on the relative motional state, which can be exploited, in analogy to [24], to realize maximally entangled states in the motional degree of freedom.

In addition, microwave sideband transitions open the way for quantum transport experiments, where continuous tunneling between adjacent lattice sites occurs when Δx is close to $d/2$, i.e., close to half the lattice spacing [38].

Finally, it is worth noting that the microwave cooling technique studied here does not strictly require the use of the “magic” wavelength for the lattice potential, but can still be operated with the same efficiency at other wavelengths, e.g., at $\lambda_L = 1064 \text{ nm}$ as we have tested. In fact, the optimal cooling efficiency occurring at around $\eta_x \sim 0.3$, see figure (8), can be reached by adjusting the polarization angle θ .

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